388

Accession number:20122915250837

Title:Development of short electrical pulses in a schottky line periodically loaded with resonant tunneling diodes

Authors:Essimbi, B.Z. (1); Jäger, D. (1)

Author affiliation:(1) ZHO, Optoelectronics, University of Duisburg-Essen, 47048 Duisburg, Germany; (2) Faculty of Science, University of Yaounde I, PO Box 812, Yaounde, Cameroon

Corresponding author:Essimbi, B.Z.(bessimb@yahoo.fr)

Source title:Journal of Infrared, Millimeter, and Terahertz Waves

Abbreviated source title: J. Infrared. Millim. Terahertz Waves

Volume:33

Issue:6

Issue date:June 2012

Publication year:2012

Pages:627-637

Language:English

ISSN:18666892

E-ISSN:18666906

Document type:Journal article (JA)

Publisher:Springer New York, 233 Springer Street, New York, NY 10013-1578, United States Abstract:The characteristics of a Schottky line periodically loaded with resonant tunneling diodes (RTDs) are discussed for the development of short electrical pulses. RTDs act as electronic switches and exhibit a pronounced N-shaped I-V characteristic even at millimetre wave frequencies. The dynamics of the line is reduced to an extended KdV equation. These dynamics are considered both within the method of perturbation and the numerical integration of the transmission equation of the line. © Springer Science+Business Media, LLC 2012.

Number of references:14

Main heading:Resonant tunneling diodes

Controlled terms:Dynamics - Numerical methods - Perturbation techniques - Pulse generators Uncontrolled terms:Electrical pulse - Electronic switches - Extended KdVequation - High-speed electronics - IV characteristics - KdV equations - Method of perturbation - Millimetre waves -Nonlinear transmission lines - Numerical integrations - Schottky - Short pulse generation -Transmission equation

Classification code:713.4 Pulse Circuits - 714.2 Semiconductor Devices and Integrated Circuits - 921 Mathematics - 921.6 Numerical Methods - 931.1 Mechanics

DOI:10.1007/s10762-012-9895-9

Database:Compendex

Compilation and indexing terms, Copyright 2012 Elsevier Inc.